74AHC3G14-Q100; 74AHCT3G14-Q100

Triple inverting Schmitt trigger

Rev. 4 — 4 December 2018

Product data sheet

1. General description

74AHC3G14-Q100 and 74AHCT3G14-Q100 are high-speed Si-gate CMOS devices. They provide three inverting buffers with Schmitt trigger action. These devices are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The AHC device has CMOS input switching levels and supply voltage range 2 V to 5.5 V.

The AHCT device has TTL input switching levels and supply voltage range 4.5 V to 5.5 V.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Symmetrical output impedance
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF; R = 0 Ω)
- Low power dissipation
- Balanced propagation delays
- Multiple package options

3. Applications

- Wave and pulse shaper for highly noisy environment
- Astable multivibrator
- · Monostable multivibrator

4. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AHC3G14DP-Q100	-40 °C to +125 °C	TSSOP8	process and comments processes,						
74AHCT3G14DP-Q100			body width 3 mm; lead length 0.5 mm						
74AHC3G14DC-Q100	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package;	SOT765-1					
74AHCT3G14DC-Q100			8 leads; body width 2.3 mm						



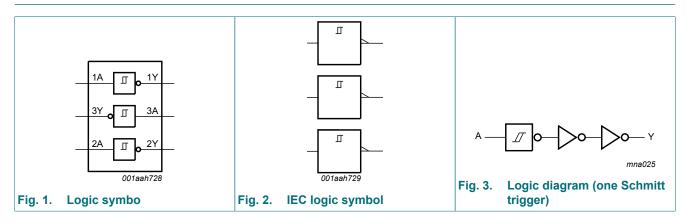
5. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AHC3G14DP-Q100	A14
74AHCT3G14DP-Q100	C14
74AHC3G14DC-Q100	A14
74AHCT3G14DC-Q100	C14

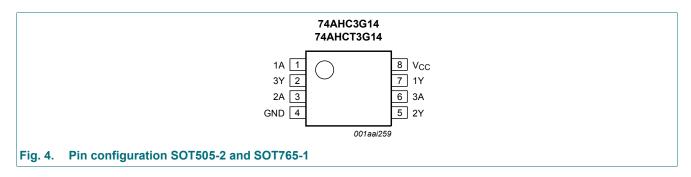
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description	
1A, 2A, 3A	1, 3, 6	data input	
GND	4	ground (0 V)	
1Y, 2Y, 3Y	7, 5, 2	data output	
V _{CC}	8 supply voltage		

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level

Input nA	Output nY
L	Н
Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	-20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC3G14-Q100			74AH	Unit		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
V _O	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

^{2]} For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly at 2.5 mW/K. For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly at 8 mW/K.

11. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC3	G14-Q100							1		
V _{OH}	HIGH-level	$V_I = V_{T+}$ or V_{T-}								
	output voltage	I _O = -50 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -50 μA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = -50 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		I_{O} = -8.0 mA; V_{CC} = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level	$V_I = V_{T+}$ or V_{T-}								
	output voltage	I _O = 50 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
Cı	input capacitance		-	1.5	10	-	10	-	10	pF
74AHCT	3G14-Q100							I		
V _{OH}	HIGH-level	$V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -8.0 mA	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$								
	output voltage	Ι _Ο = 50 μΑ	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
lı	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10	-	40	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_I = 3.4 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 5.5 \text{ V}$	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance		-	1.5	10	-	10	-	10	pF

11.1. Transfer characteristics

Table 8. Transfer characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). See Fig. 7 and Fig. 8.

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC3	G14-Q100								'	
V _{T+}	positive-going	V _{CC} = 3.0 V	-	-	2.2	-	2.2	-	2.2	V
	threshold voltage	V _{CC} = 4.5 V	-	-	3.15	-	3.15	-	3.15	V
		V _{CC} = 5.5 V	-	-	3.85	-	3.85	-	3.85	V
V _{T-}	negative-going	V _{CC} = 3.0 V	0.9	-	-	0.9	-	0.9	-	V
	threshold voltage	V _{CC} = 4.5 V	1.35	-	-	1.35	-	1.35	-	V
		V _{CC} = 5.5 V	1.65	-	-	1.65	-	1.65	-	V
V _H	hysteresis voltage	V _{CC} = 3.0 V	0.3	-	1.2	0.3	1.2	0.25	1.2	V
		V _{CC} = 4.5 V	0.4	-	1.4	0.4	1.4	0.35	1.4	V
		V _{CC} = 5.5 V	0.5	-	1.6	0.5	1.6	0.45	1.6	V
74AHCT	3G14-Q100			l	l				'	
V _{T+}	positive-going	V _{CC} = 4.5 V	-	-	2.0	-	2.0	-	2.0	V
	threshold voltage	V _{CC} = 5.5 V	-	-	2.0	-	2.0	-	2.0	V
V _{T-}	negative-going	V _{CC} = 4.5 V	0.5	-	-	0.5	-	0.5	-	V
threshold vo	threshold voltage	V _{CC} = 5.5 V	0.6	-	-	0.6	-	0.6	-	V
V _H	hysteresis voltage	V _{CC} = 4.5 V	0.4	-	1.4	0.4	1.4	0.35	1.4	V
		V _{CC} = 5.5 V	0.4	-	1.6	0.4	1.6	0.35	1.6	V

12. Dynamic characteristics

Table 9. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 3.0$ ns; for test circuit see Fig. 6.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
				Min	Тур	Max	Min	Max	Min	Max	
74AHC3	G14-Q100									•	
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
	delay	V _{CC} = 3.0 V to 3.6 V	[2]								
		C _L = 15 pF		-	4.2	12.8	1.0	15.0	1.0	16.5	ns
		C _L = 50 pF		-	6.0	16.3	1.0	18.5	1.0	20.5	ns
		V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	3.2	8.6	1.0	10.0	1.0	11.0	ns
		C _L = 50 pF		-	4.6	10.6	1.0	12.0	1.0	13.5	ns
C _{PD}	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}$; $f_i = 1 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$	[4]	-	10	-	-	-	-	-	pF
74AHCT	3G14-Q100									•	
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
	delay	V _{CC} = 4.5 V to 5.5 V	[3]								
		C _L = 15 pF		-	4.1	7.0	1.0	8.0	1.0	9.0	ns
		C _L = 50 pF		-	5.9	8.5	1.0	10.0	1.0	11.0	ns
C _{PD}	power dissipation capacitance	per buffer; $C_L = 50 \text{ pF}$; $f_i = 1 \text{ MHz}$; $V_I = \text{GND to } V_{CC}$	[4]	-	12	-	-	-	-	-	pF

- t_{pd} is the same as t_{PLH} and $t_{PHL}.$ Typical values are measured at V $_{CC}$ = 3.3 V.
- Typical values are measured at $V_{CC} = 5.0 \text{ V}$. Typical values are measured at $V_{CC} = 5.0 \text{ V}$. C_{PD} is used to determine the dynamic power dissipation P_D (μ W). $P_D = C_{PD} \times {V_{CC}}^2 \times f_i + \Sigma (C_L \times {V_{CC}}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveform and test circuit

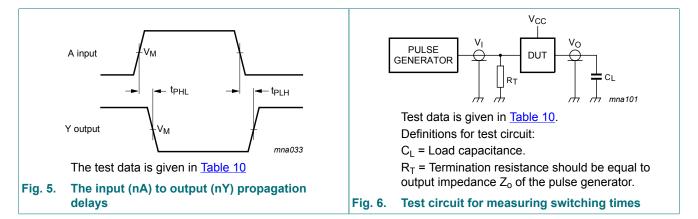
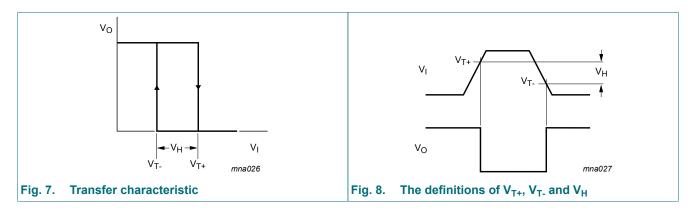


Table 10. Test data

Tuble 10. Test data								
Type number	Input	Input						
	V _I	V _I V _M V						
74AHC3G14-Q100	GND to V _{CC}	0.5 x V _{CC}	0.5 x V _{CC}					
74AHCT3G14-Q100	GND to 3.0 V	1.5 V	0.5 x V _{CC}					

12.2. Transfer characteristic waveforms



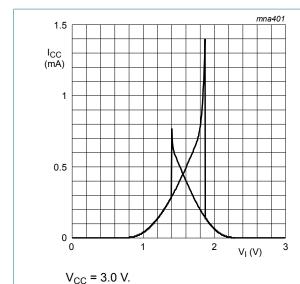


Fig. 9. Typical 74AHC3G14-Q100 transfer characteristics

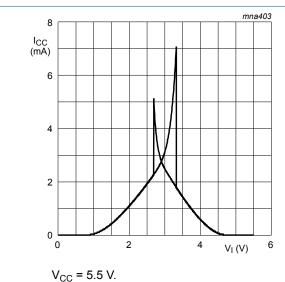
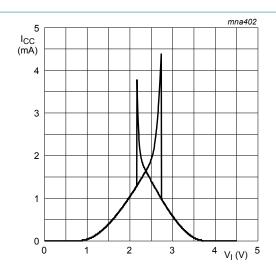
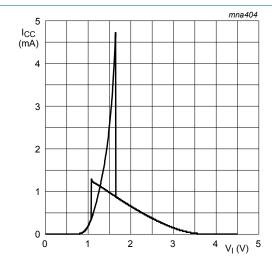


Fig. 11. Typical 74AHC3G14-Q100 transfer characteristics



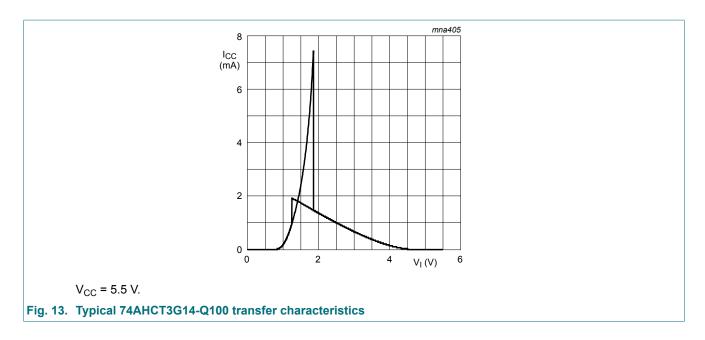
 $V_{\rm CC}$ = 4.5 V.

Fig. 10. Typical 74AHC3G14-Q100 transfer characteristics



 $V_{CC} = 4.5 \text{ V}.$

Fig. 12. Typical 74AHCT3G14-Q100 transfer characteristics



13. Application information

The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i x (t_r x \Delta I_{CC(AV)} + t_f x \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μ W);

 f_i = input frequency (MHz);

 t_r = input rise time (ns); 10 % to 90 %;

 t_f = input fall time (ns); 90 % to 10 %;

 $\Delta I_{CC(AV)}$ = average additional supply current (μA).

ΔI_{CC(AV)} differs with positive or negative input transitions, as shown in Fig. 14 and Fig. 15.

For 74AHC3G14-Q100 and 74AHCT3G14-Q100 used in relaxation oscillator circuit, see Fig. 16.

Note to the application information:

1. All values given are typical unless otherwise specified.

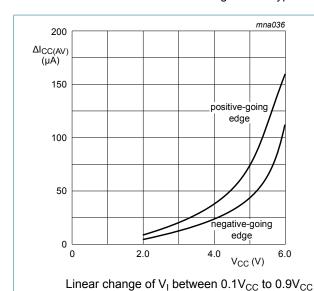
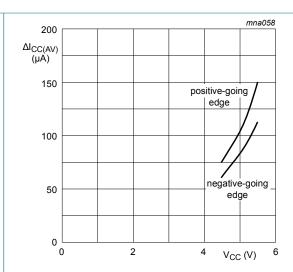
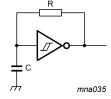


Fig. 14. Average additional I_{CC} for 74AHC3G14-Q100 Schmitt trigger devices



Linear change of V_I between 0.1V_{CC} to 0.9V_{CC}

Fig. 15. Average additional I_{CC} for 74AHCT3G14-Q100 Schmitt trigger devices



For 74AHC3G14-Q100: $f = \frac{1}{T} \approx \frac{1}{0.55 \times RC}$ For 74AHCT3G14-Q100: $f = \frac{1}{T} \approx \frac{1}{0.60 \times RC}$

Fig. 16. Relaxation oscillator using the 74AHC3G14-Q100 and 74AHCT3G14-Q100

14. Package outline

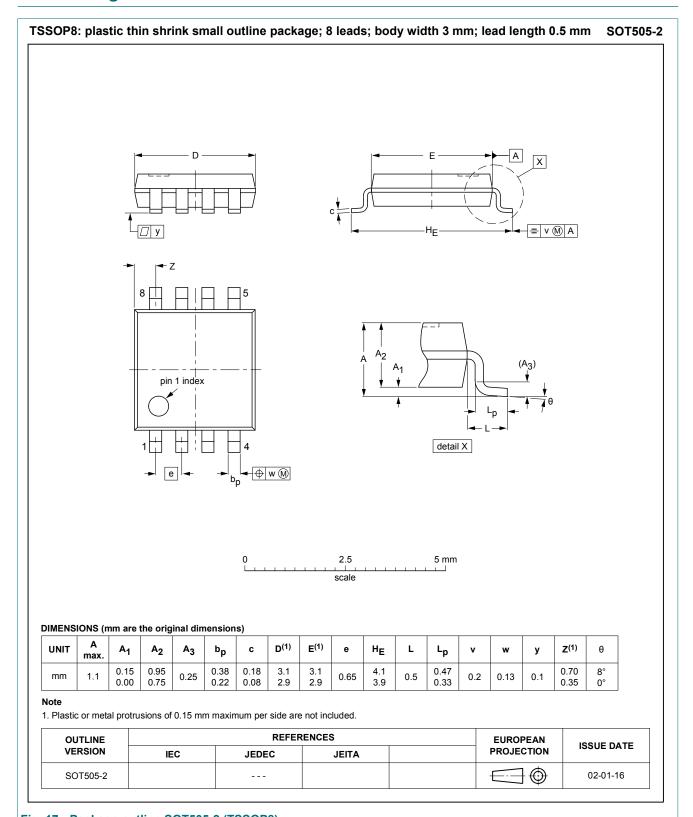


Fig. 17. Package outline SOT505-2 (TSSOP8)

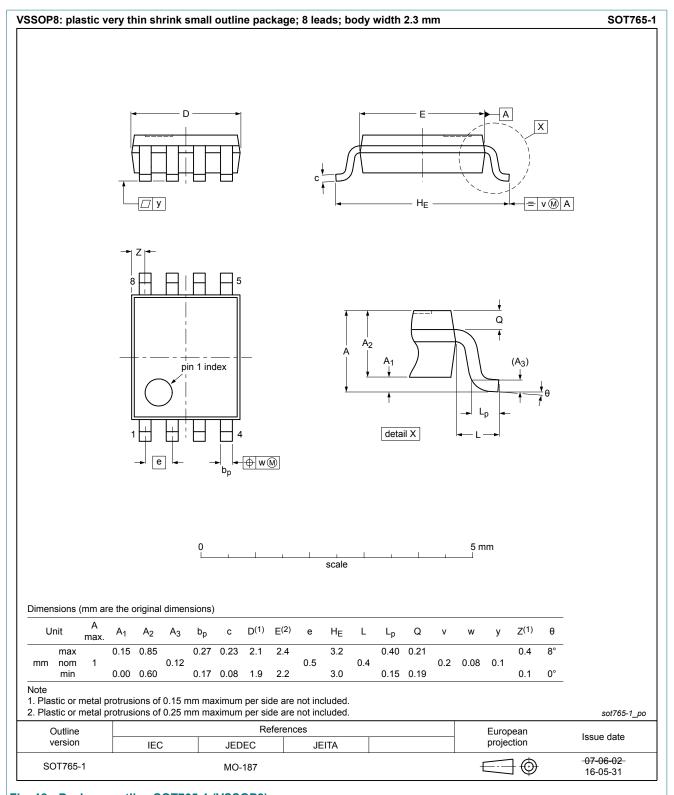


Fig. 18. Package outline SOT765-1 (VSSOP8)

15. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74AHC_AHCT3G14_Q100 v.4	20181204	Product data sheet	-	74AHC_AHCT3G14_Q100 v.3				
Modifications:	guidelines of to Legal texts ha	nave been adapted to the new company name where appropriate. r 74AHC3G14GD-Q100 and 74AHCT3G14GD-Q100 (SOT996-2/						
74AHC_AHCT3G14_Q100 v.3	20130916	Product data sheet	-	74AHC_AHCT3G14_Q100 v.2				
Modifications:	Added type number 74AHC3G14GD-Q100 and 74AHCT3G14GD-Q100.							
74AHC_AHCT3G14_Q100 v.2	20130128	Product data sheet	-	74AHC_AHCT3G14_Q100 v.1				
74AHC_AHCT3G14_Q100 v.1	20121001	Product data sheet	-	-				

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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